

L Number	Hits	Search Text	DB	Time stamp
-	2	5545915.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/21 16:28
-	2	5895951.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/21 16:30
-	2	5879968.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/21 16:52
-	9	("4879254"   "4898835"   "4987098"   "5023191"   "5072266"   "5164327"   "5298442"   "5453390"   "5486715").PN.	USPAT	2003/07/21 16:30
-	4	("4430792"   "4503598"   "4567641"   "4598461").PN.	USPAT	2003/07/21 16:48
-	2	4879254.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/21 16:52
-	4	("4430792"   "4503598"   "4567641"   "4598461").PN.	USPAT	2003/07/21 16:53
-	57	4879254.URPN.	USPAT	2003/12/17 18:21
-	14	("4231811"   "4502069"   "4516143"   "4598461"   "4853345"   "4879254"   "4920064"   "4985740"   "5034336"   "5155052"   "5173435"   "5302537"   "5731604"   "5795793").PN.	USPAT	2003/07/21 17:04
-	0	jp-215025-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/22 17:12
-	0	jp-9215025-\$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/22 17:12
-	58	4879254.URPN.	USPAT	2003/12/17 18:19
-	58	4879254.URPN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/17 18:22
-	52	4879254.URPN. and (@ad<19970808 or @rlad<19970808)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/17 18:23
-	0	5910668.URPN.	USPAT	2003/12/17 18:30
-	0	5910668.URPN.	USPAT	2003/12/17 18:30
-	11	("4853345"   "4879254"   "4960723"   "5079602"   "5155052"   "5178370"   "5179032"   "5262336"   "5366914"   "5451531"   "5731604").PN.	USPAT	2003/12/17 18:30
-	2	5631484.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/21 17:03
-	27	5631484.URPN.	USPAT	2004/06/21 16:29
-	19412	power with mosfet	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/23 14:59
-	218	(power with mosfet) with planar	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/21 17:04

-	88	((power with mosfet) with planar) and (sidewall or (side adj wall))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/21 17:06
-	19	((power with mosfet) with planar) and (sidewall or (side adj wall))) and (@ad<19970808 or @rlad<19970808)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/23 15:01
-	7828	power adj mosfet	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/23 15:00
-	181	(power adj mosfet) with planar	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/23 15:00
-	59	((power adj mosfet) with planar) and (@ad<19970808 or @rlad<19970808)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/23 15:06
-	384	(power adj mosfet) and (sidewall or (side adj wall)) and (@ad<19970808 or @rlad<19970808)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/23 15:08
-	237	((power adj mosfet) and (sidewall or (side adj wall)) and (@ad<19970808 or @rlad<19970808)) and implant\$5 and etch\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/23 15:08